

RELAY DRIVERS, LAMP DRIVERS,  
MOTOR DRIVERS APPLICATION.

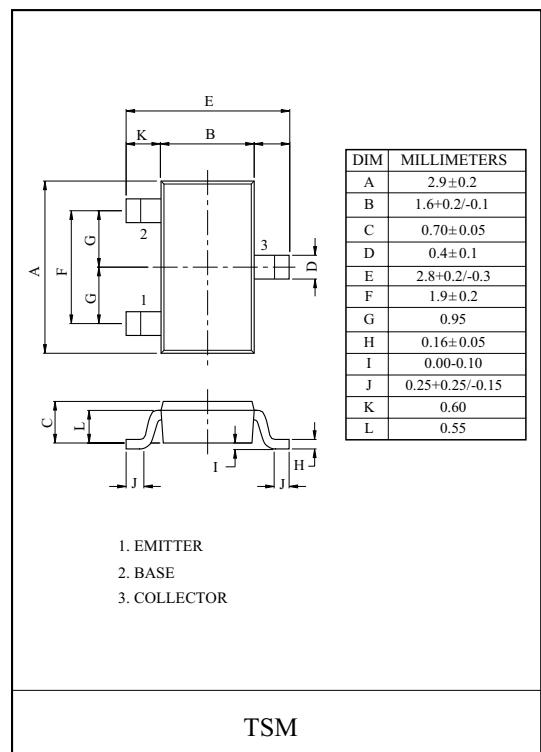
### FEATURES

- Adoption of MBIT Processes.
- Large Current Capacitance.
- Low Collector-to-Emitter Saturation Voltage.
- High-Speed Switching.
- Ultrasmall Package Facilitates Miniaturization in end Products.
- High Allowable Power Dissipation.
- Complementary to KTA1551T.

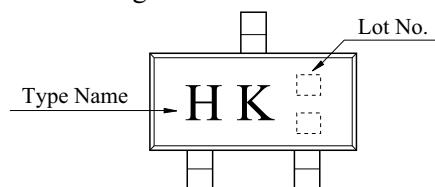
### MAXIMUM RATING (Ta=25 °C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V <sub>CBO</sub>	80	V
Collector-Emitter Voltage		V <sub>CES</sub>	80	V
		V <sub>CEO</sub>	50	
Emitter-Base Voltage		V <sub>EBO</sub>	5	V
Collector Current	DC	I <sub>C</sub>	1.0	A
	Pulse	I <sub>CP</sub>	3	
Base Current		I <sub>B</sub>	200	mA
Collector Power Dissipation		P <sub>C</sub> *	0.9	W
Junction Temperature		T <sub>j</sub>	150	°C
Storage Temperature Range		T <sub>stg</sub>	-55 ~ 150	°C

\* Package mounted on a ceramic board (600mm<sup>2</sup> × 0.8mm)



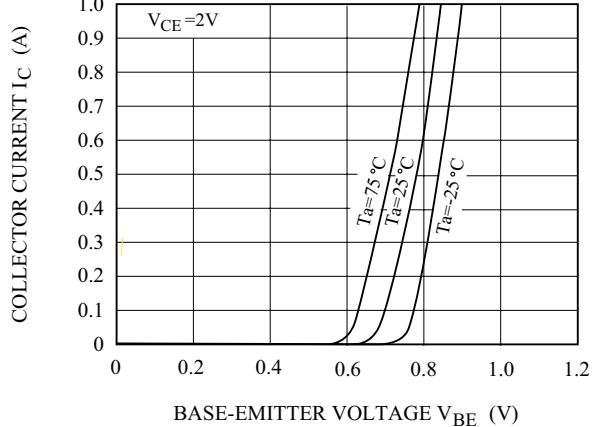
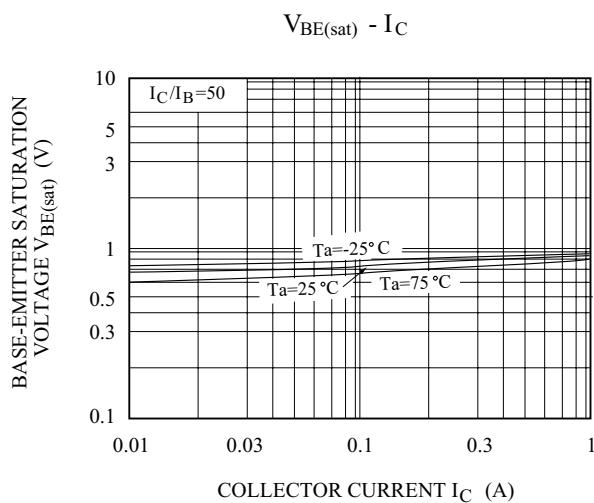
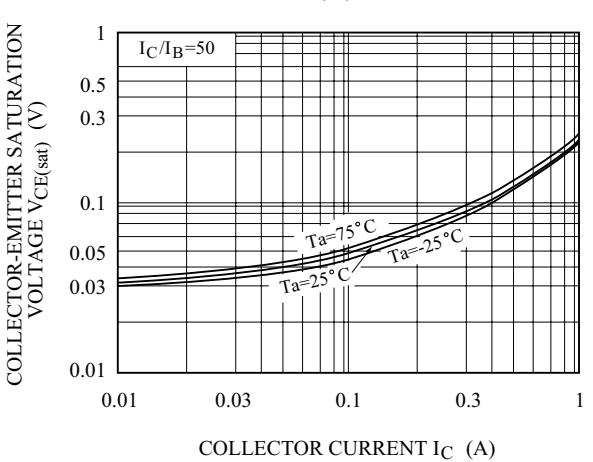
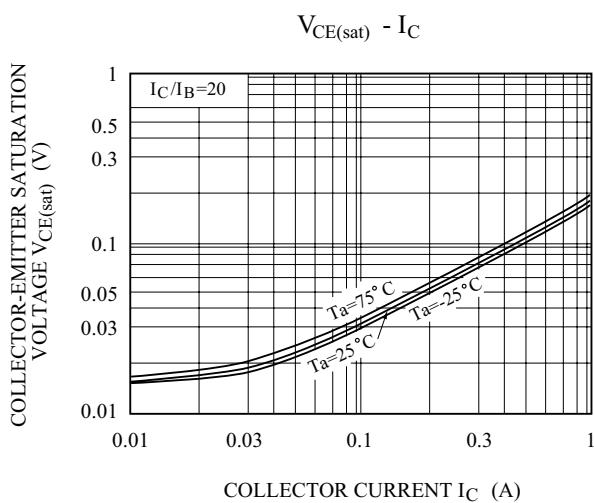
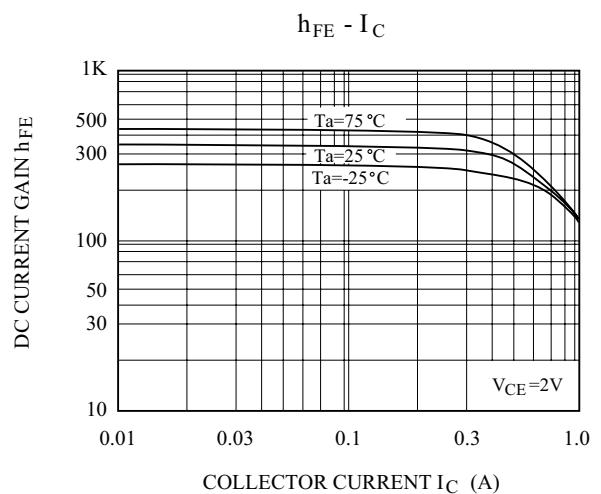
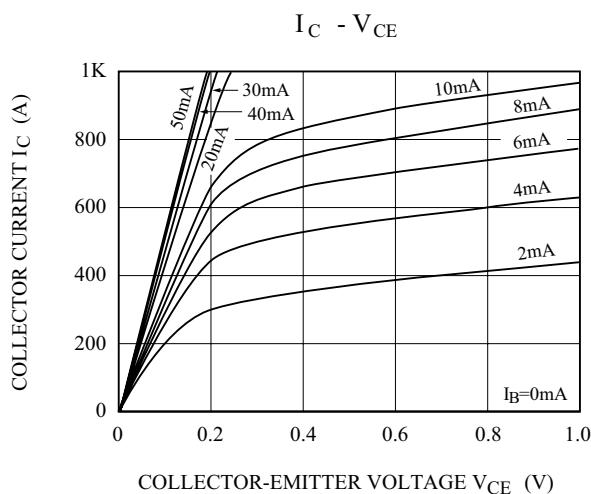
### Marking



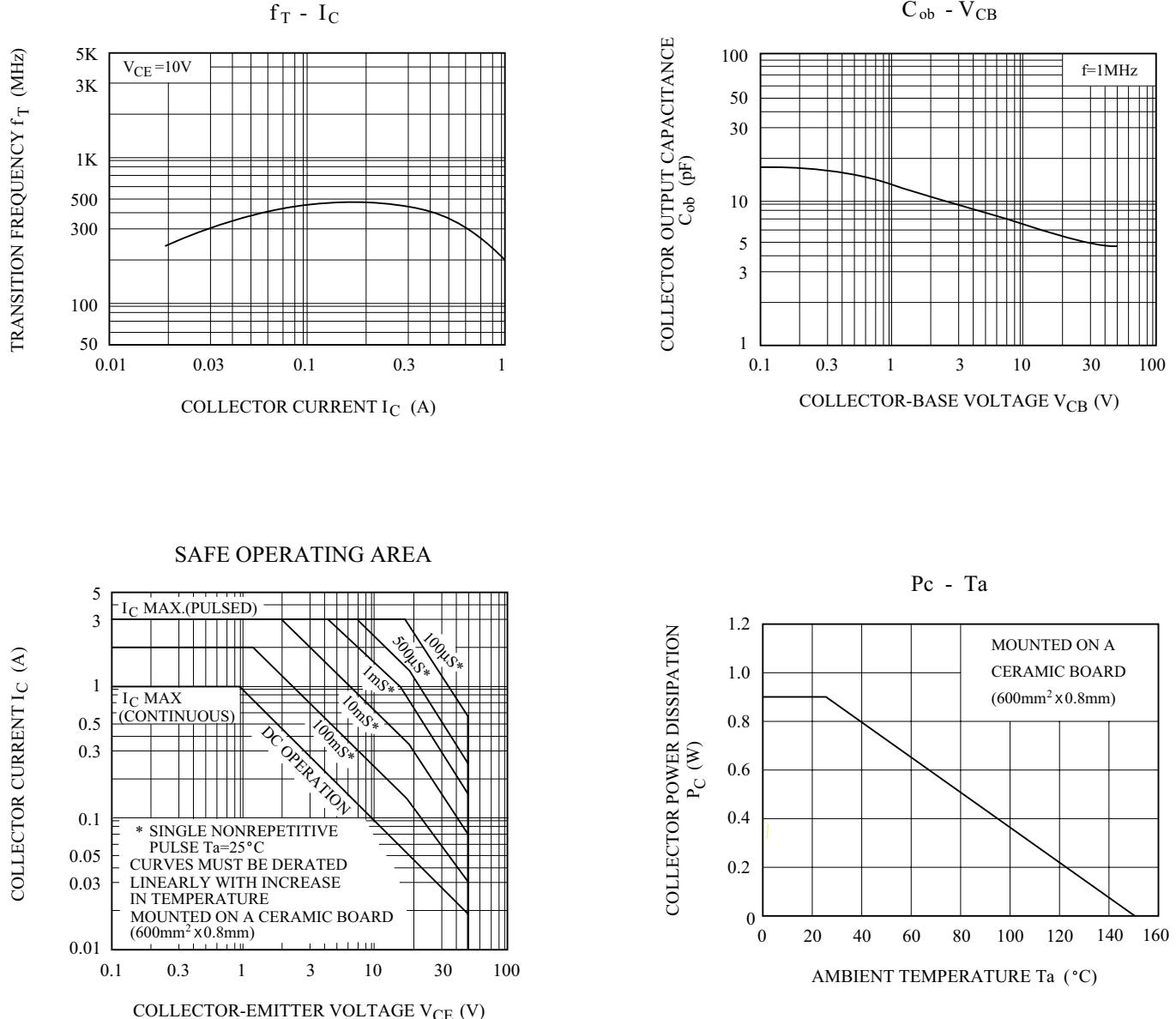
### ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I <sub>CBO</sub>	V <sub>CB</sub> =40V, I <sub>E</sub> =0	-	-	0.1	μA
Emitter Cut-off Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0	-	-	0.1	μA
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =10μA, I <sub>E</sub> =0	80	-	-	V
Collector-Emitter Breakdown Voltage	V <sub>(BR)CES</sub>	I <sub>C</sub> =100μA, V <sub>BE</sub> =0	80	-	-	V
	V <sub>(BR)CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	50	-	-	V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =10μA, I <sub>C</sub> =0	5	-	-	V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)1</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =10mA	-	130	190	mV
	V <sub>CE(sat)2</sub>	I <sub>C</sub> =300mA, I <sub>B</sub> =6mA	-	90	135	mV
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =10mA	-	0.81	1.2	V
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA	200	-	560	
Transition Frequency	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =300mA	-	420	-	MHz
Collector Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz	-	6	-	pF
Switching Time	Turn-On Time	t <sub>on</sub>				
	Storage Time	t <sub>stg</sub>				
	Fall Time	t <sub>f</sub>				

# KTC3551T



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